

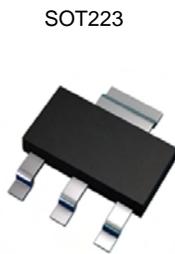
30V NPN SILICON PLANAR MEDIUM POWER TRANSISTOR IN SOT223

Features

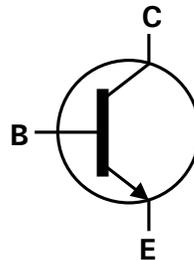
- $BV_{CEO} > 30V$
- Max Continuous Current $I_C = 1A$
- Low Saturation Voltage
- Complementary PNP Type: FZT589
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP capable (Note 4)**

Mechanical Data

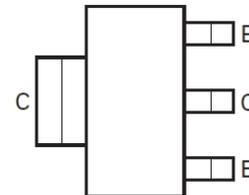
- Case: SOT223
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.112 grams (approximate)



Top View



Device Symbol



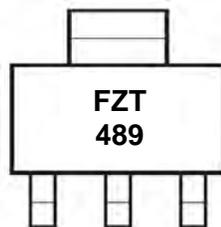
Top View
Pin-Out

Ordering Information (Notes 4 & 5)

| Product | Compliance | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|-----------|------------|---------|--------------------|-----------------|-------------------|
| FZT489TA | AEC-Q101 | FZT489 | 7 | 12 | 1,000 |
| FZT489QTA | Automotive | FZT489 | 7 | 12 | 1,000 |

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
 5. For packaging details, go to our website at <http://www.diodes.com>

Marking Information



FZT489 = Product Type Marking Code

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | 50 | V |
| Collector-Emitter Voltage | V _{CEO} | 30 | V |
| Emitter-Base Voltage | V _{EBO} | 7 | V |
| Continuous Collector Current | I _C | 1 | A |
| Base Current | I _B | 200 | mA |
| Peak Pulse Current | I _{CM} | 4 | A |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

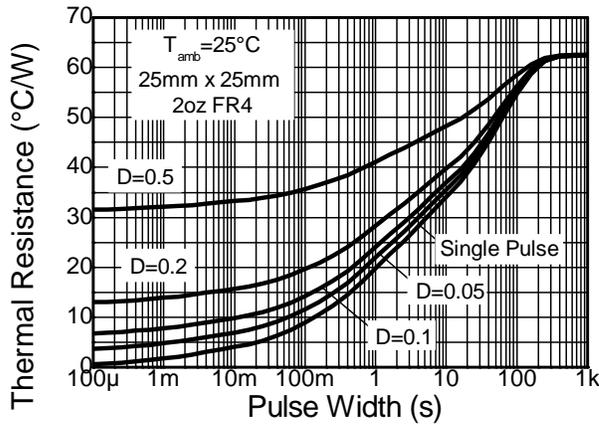
| Characteristic | Symbol | Value | Unit | |
|--|-----------------------------------|-------------|------|------|
| Power Dissipation | P _D | (Note 6) | 2 | W |
| | | (Note 7) | 3 | W |
| Thermal Resistance, Junction to Ambient | R _{θJA} | (Note 6) | 62.5 | °C/W |
| | | (Note 7) | 41.7 | °C/W |
| Thermal Resistance, Junction to Leads (Note 8) | R _{θJL} | 19.41 | °C/W | |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C | |

ESD Ratings (Note 9)

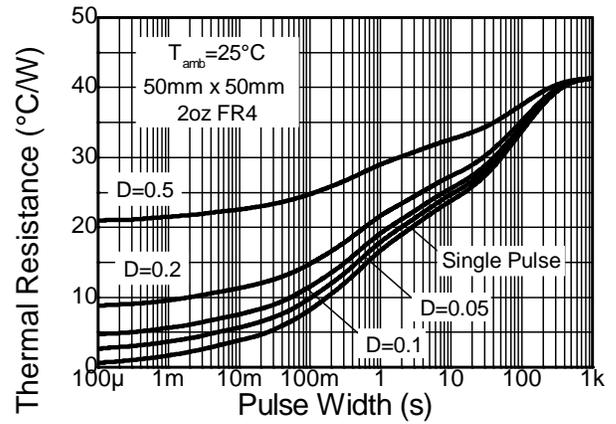
| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|---------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | ≥ 8,000 | V | 3B |
| Electrostatic Discharge - Machine Model | ESD MM | ≥ 400 | V | C |

- Notes:
6. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; device measured when operating in steady state condition.
 7. Same as note (6), except the device is mounted on 50mm X 50mm single sided 2oz weight copper.
 8. Thermal resistance from junction to solder-point (at the end of the collector lead).
 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

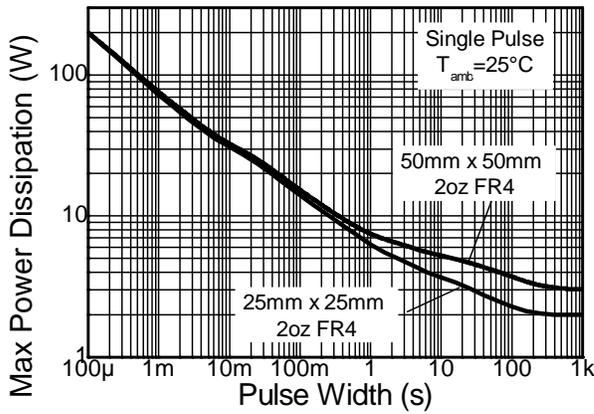
Thermal Characteristics and Derating Characteristics



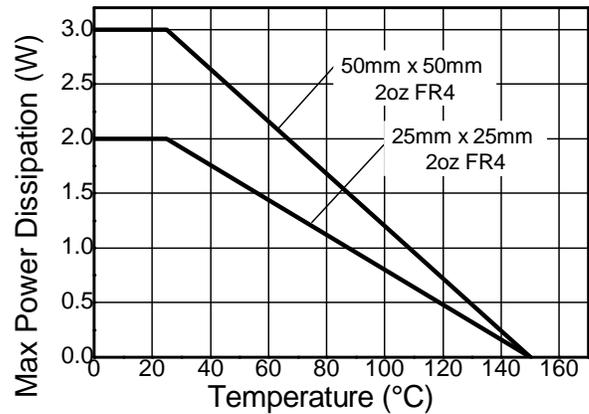
Transient Thermal Impedance



Transient Thermal Impedance



Pulse Power Dissipation



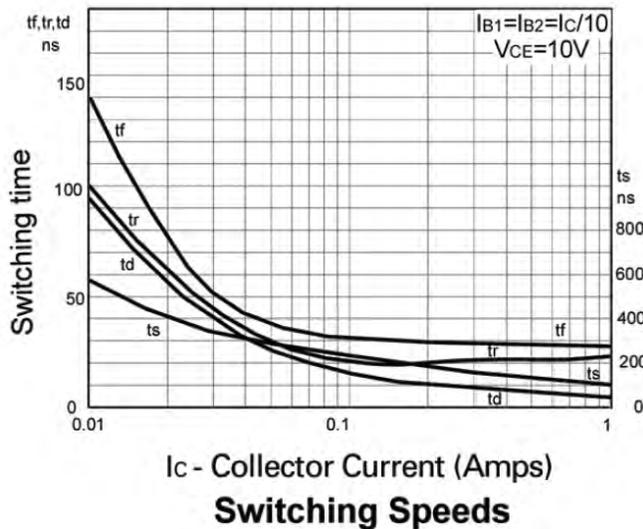
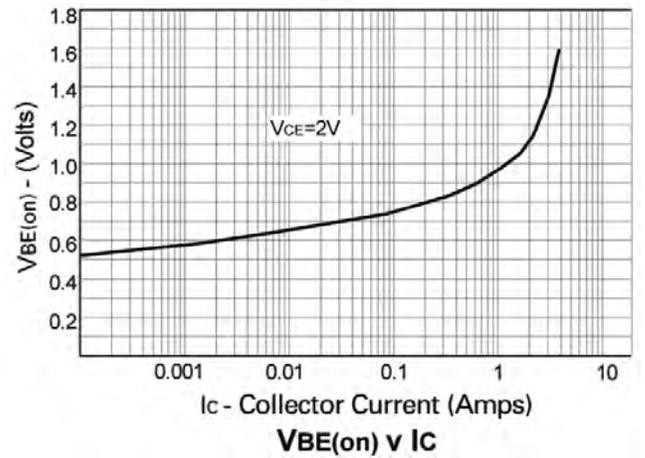
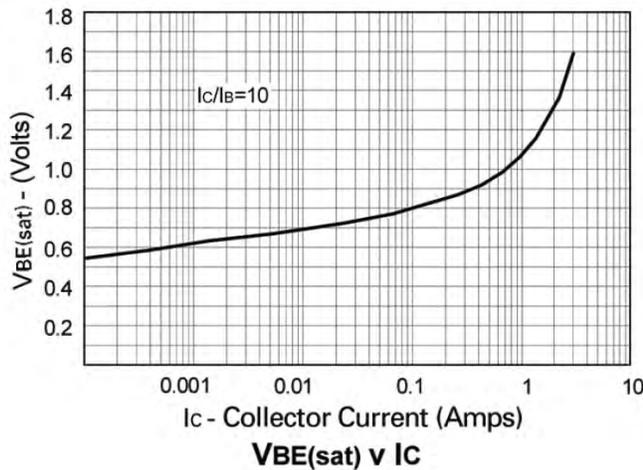
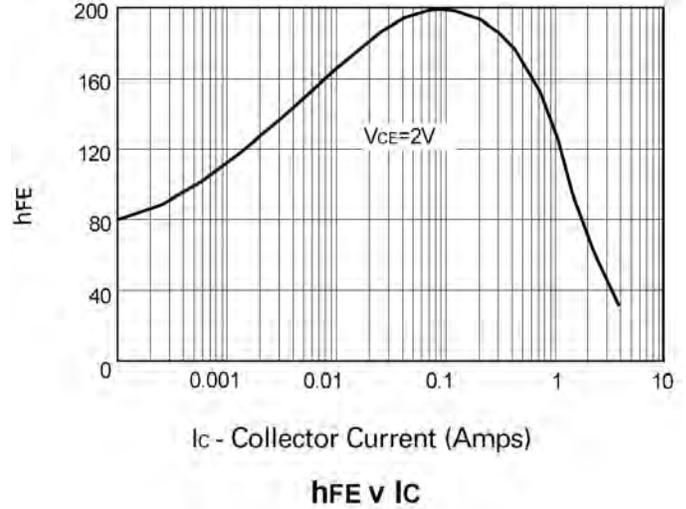
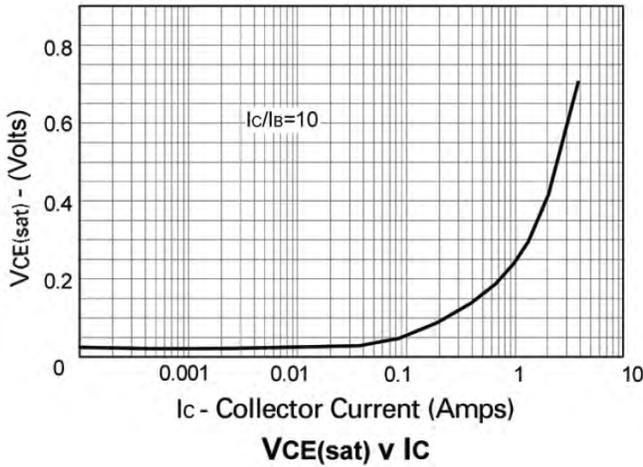
Derating Curve

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|--|----------------------|------------------------|------------------|--------------------|------|---|
| Collector-Base Breakdown Voltage | BV _{CBO} | 50 | – | – | V | I _C = 100μA |
| Collector-Emitter Breakdown Voltage (Note 10) | BV _{CEO} | 30 | – | – | V | I _C = 10mA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | 7 | – | – | V | I _E = 100μA |
| Collector Cut-off Current | I _{CBO} | – | – | 100 | nA | V _{CB} = 30V |
| Collector Cut-off Current | I _{CES} | – | – | 100 | nA | V _{CE} = 30V |
| Emitter Cut-off Current | I _{EBO} | – | – | 100 | nA | V _{EB} = 4V |
| Collector-Emitter Saturation Voltage (Note 10) | V _{CE(sat)} | – | – | 0.3 0.6 | V | I _C = 1A, I _B = 100mA I _C = 2A, I _B = 200mA |
| Base-Emitter Saturation Voltage (Note 10) | V _{BE(sat)} | – | – | 1.1 | V | I _C = 1A, I _B = 100mA |
| Base-Emitter Turn-On Voltage (Note 10) | V _{BE(on)} | – | – | 1.0 | V | I _C = 1A, V _{CE} = 2V |
| DC Current Gain (Note 10) | h _{FE} | 100 100 60 20 | – – – – | – 300 – – | – | I _C = 1mA, V _{CE} = 2V I _C = 1A, V _{CE} = 2V I _C = 2A, V _{CE} = 2V I _C = 4A, V _{CE} = 2V |
| Current Gain-Bandwidth Product (Note 10) | f _T | 150 | – | – | MHz | V _{CE} = 10V, I _C = 50mA f = 100MHz |
| Output Capacitance (Note 10) | C _{obo} | – | – | 10 | pF | V _{CB} = 10V, f = 1MHz |

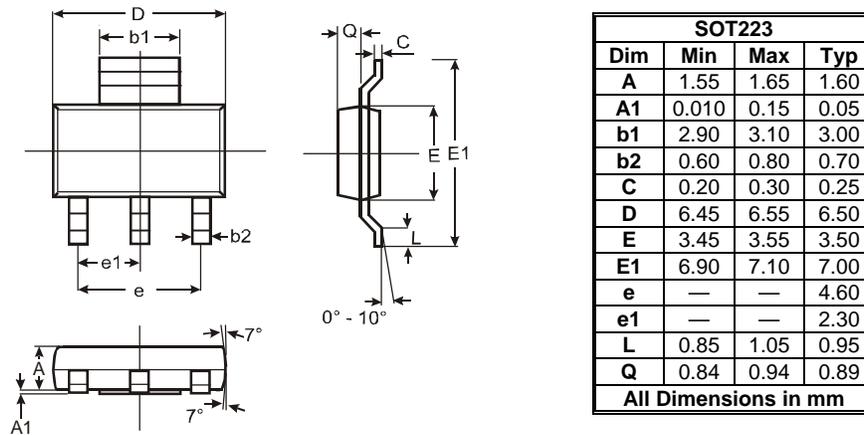
Notes: 10. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



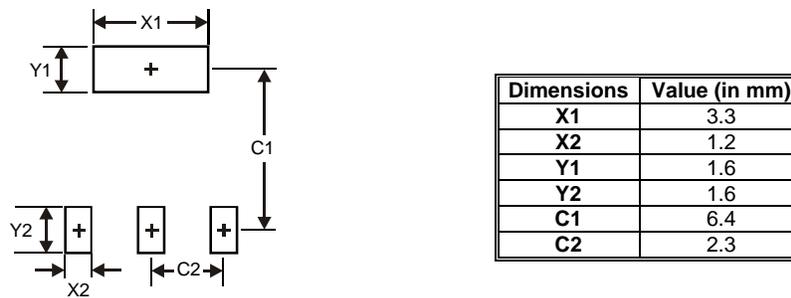
Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



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